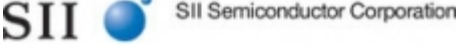
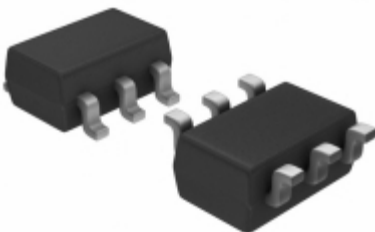



| | | |
|---|--------------------------------|--|
|  | S-8261ABPMD-G3PT2G | |
| | Hersteller-Teilenummer: | S-8261ABPMD-G3PT2G |
|  | Hersteller / Marke: | SII Semiconductor Corporation |
| | Teil der Beschreibung: | IC LI-ION BATT PROTECT SOT23-6 |
| | Datenblätter: |  S-8261ABPMD-G3PT2G.pdf |
| | RoHs Status: | Bleifrei / RoHS-konform |
| | Lagerzustand: | New original, 3808 pcs Stock Available. |
| | Liefern von: | Hong Kong |
| | Versandweg: | DHL/Fedex/TNT/UPS/EMS |
| Image may be representation. See specs for product details. | | |

Spezifikationen

| | |
|-------------------------|--|
| Teilenummer | S-8261ABPMD-G3PT2G |
| Hersteller | SII Semiconductor Corporation |
| Beschreibung | IC LI-ION BATT PROTECT SOT23-6 |
| Kategorie | Integrierte Schaltungen (ICs) > PMIC - |
| Teilstatus | 3808 pcs Stock |
| Serie | - |
| Betriebstemperatur | -40°C ~ 85°C (TA) |
| Batterie-Chemie | Lithium-Ion/Polymer |
| Anzahl der Zellen, | 1 |
| Schnittstelle | - |
| Verpackung / Gehäuse | SOT-23-6 |
| Supplier Device-Gehäuse | SOT-23-6 |
| Funktion | Battery Protection |
| Fehlerschutz | Over Current, Short Circuit |
| Verpackung | Tape & Reel (TR) |


































S-8261ABPMD-G3PT2G ist neu im Original, Suche S-8261ABPMD-G3PT2G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie S-8261ABPMD-G3PT2G SII Semiconductor Corporation mit Garantie und Vertrauen. Anfrage S-8261ABPMD-G3PT2G: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|---|---|--|---|
|  <p>S-8261ABPMD-G3P-T2G SII Semiconductor Corporation S-8261ABPMD-G3P-T2G SII</p> |  <p>S-8261ABOBD-G30-TF SEIKO SEIKO SOT23</p> |  <p>S-8261ABOBD-G30TFG SII Semiconductor Corporation IC LI-ION BATT PROTECT SOT23-6</p> |  <p>S-8261ABNMD-G3NT2G SII Semiconductor Corporation IC LI-ION BATT PROTECT SOT23-6</p> |
|  <p>S-8261ABRMD-G3R-T2 SEIKO S-8261ABRMD-G3R-T2 SEIKO</p> |  <p>S-8261ABRMD-G3RT2G SII Semiconductor Corporation IC LI-ION BATT PROTECT SOT23-6</p> |  <p>S-8261ABRMD-G3RT2 SEIKO S-8261ABRMD-G3RT2 SEIKO</p> |  <p>S-8261ABPMD-G3PT2U SII Semiconductor Corporation IC BATT PROTECTION</p> |

heiße Teile

Mehr

- | | | | | |
|--|--|--|--|--|
|  S-8261AAOMD-G20T2S |  S-8261AAOMD-G20T2S |  S-8261AAOMD-G20T2Z |  S-8261AAPMD-G2PT2G |  S-8261AARBD-G2R-TF |
|  S-8261AASMD-G2ST2G |  S-8261AAVBD-G2V-TF |  S-8261AAXMD-G2X-T2 |  S-8261AAXMD-G2XT2U |  S-8261AAZMD-G2ZT2S |
|  S-8261ABAMD-G3AT2S |  S-8261ABAMD-G3AT2U |  S-8261ABEBD-G3E |  S-8261ABEBD-G3E-TF |  S-8261ABEBD-G3ETF2 |
|  S-8261ABEBD-G3ETFZ |  S-8261ABGBD-G3G-TF |  S-8261ABGBD-G3GTFZ |  S-8261ABHBD-GH-TF |  S-8261ABIMD-G3IT2S |
|  S-8261ABJMD |  S-8261ABJMD-G3JT2G |  S-8261ABJMD-G3JT2S |  S-8261ABLMD-G3LT2U |  S-8261ABMMD-G3M-T2 |
|  S-8261ABPMD-G3PT2S |  S-8261ABRMD-G3R-T2 |  S-8261ABRMD-G3RT2 |  S-8261ABRMD-G3RT2G |  S-8261ABRMD-G3RT2S |
|  S-8261ABSMD-G3S-T2 |  S-8261ABTMD-G3TT2G |  S-8261ACEMD-G4ET2G |  S-8261ACEMD-G4ET2S |  S-8261ACFMD-G4FT2G |
|  S-8261ACHMD-G4HT2G |  S-8261ACJMD-G4JT2S |  S-8261ACMMD-G4MT2G |  S-8261ACPMMD-G4PT2S |  S-8261ACTMD-G4TT2U |
|  S-8261BAL-M6T1U |  S-8261BAQ-M6T1U |  S-8261BAT-M6T1U |  S-8261CAJ-I6T1U |  S-8261CAP-I6T1U |
|  S-8261CBA-I6T1U |  S-8261CBI-I6T1U |  S-8261CBS-I6T1U |  S-8261DAA-M6T1U |  S-8261DAM-M6T1U |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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